

FEATURES

FE	EATURES	DGG OR DGV	PACKAGE
٠	Member of the Texas Instruments Widebus™	(TOP V	
	Family		
•	TI-OPC™ Circuitry Limits Ringing on	1DIR 🛛 1	56 0 1 OE
	Unevenly Loaded Backplanes	1A1 🛛 2	55 🛛 1B1
•	OEC™ Circuitry Improves Signal Integrity and	1A2 🛛 3	54 🛛 1B2
	Reduces Electromagnetic Interference	GND 4	53 🛛 GND
•	Bidirectional Interface Between GTLP Signal	1A3 🛛 5	52 [1B3
•	Levels and LVTTL Logic Levels	1A4 🛛 6	51 [1B4
-	LVTTL Interfaces Are 5-V Tolerant	V _{CC} []7	50 🛛 V _{CC}
•		GND 8	49 GND
•	High-Drive GTLP Outputs (100 mA)	1A5 🛛 9	48 [1B5
•	LVTTL Outputs (–24 mA/24 mA)	1A6 🛛 10	47 [1B6
•	Variable Edge-Rate Control (ERC) Input	GND 🛛 11	46 GND
	Selects GTLP Rise and Fall Times for Optimal	1A7 🛛 12	45 [1B7
	Data-Transfer Rate and Signal Integrity in	1A8 🛛 13	44 [1B8
	Distributed Loads	GND 14	43 BIAS V _{CC}
•	I _{off} , Power-Up 3-State, and BIAS V _{CC} Support	ERC [] 15	42 🛛 V _{REF}
	Live Insertion	2A1 🛛 16	41 2 2B1
•	Bus Hold on A-Port Data Inputs	2A2 🛛 17	40 0 2B2
	•	GND 18	39 GND
•	Distributed V _{CC} and GND Pins Minimize High-Speed Switching Noise	2A3 19	38 2B3
		2A4 20	37 2B4
•	Latch-Up Performance Exceeds 100 mA Per	GND 21	36 GND
	JESD 78, Class II		35 V _{CC}
		2A5 23	34 2B5
		2A6 24	33 2B6
		GND 25	32 GND
		2A7 2 6	31 2B7
		2A8 27	30 2B8
		2DIR [28	29 20E

DESCRIPTION/ORDERING INFORMATION

The SN74GTLPH1645 is a high-drive, 16-bit bus transceiver that provides LVTTL-to-GTLP and GTLP-to-LVTTL signal-level translation. It is partitioned as two 8-bit transceivers. The device provides a high-speed interface between cards operating at LVTTL logic levels and a backplane operating at GTLP signal levels. High-speed (about three times faster than standard LVTTL or TTL) backplane operation is a direct result of GTLP's reduced output swing (<1 V), reduced input threshold levels, improved differential input, OEC™ circuitry, and TI-OPC™ circuitry. Improved GTLP OEC and TI-OPC circuits minimize bus-settling time and have been designed and tested using several backplane models. The high drive allows incident-wave switching in heavily loaded backplanes with equivalent load impedance down to 11 Ω .

GTLP is the Texas Instruments derivative of the Gunning Transceiver Logic (GTL) JEDEC standard JESD 8-3. The ac specification of the SN74GTLPH1645 is given only at the preferred higher noise-margin GTLP, but the user has the flexibility of using this device at either GTL ($V_{TT} = 1.2$ V and $V_{REF} = 0.8$ V) or GTLP ($V_{TT} = 1.5$ V and $V_{RFF} = 1 \text{ V}$) signal levels.

Normally, the B port operates at GTLP signal levels. The A-port and control inputs operate at LVTTL logic levels, but are 5-V tolerant and are compatible with TTL and 5-V CMOS inputs. V_{REF} is the B-port differential input reference voltage.



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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

This device is fully specified for live-insertion applications using I_{off} , power-up 3-state, and BIAS V_{CC} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict. The BIAS V_{CC} circuitry precharges and preconditions the B-port input/output connections, preventing disturbance of active data on the backplane during card insertion or removal, and permits true live-insertion capability.

This GTLP device features TI-OPC circuitry, which actively limits the overshoot caused by improperly terminated backplanes, unevenly distributed cards, or empty slots during low-to-high signal transitions. This improves signal integrity, which allows adequate noise margin to be maintained at higher frequencies.

High-drive GTLP backplane interface devices feature adjustable edge-rate control (\overline{ERC}). Changing the \overline{ERC} input voltage between GND and V_{CC} adjusts the B-port output rise and fall times. This allows the designer to optimize system data-transfer rate and signal integrity to the backplane load.

Active bus-hold circuitry holds unused or undriven LVTTL data inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

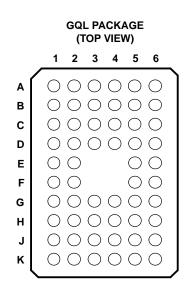
When V_{CC} is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, the output-enable (\overline{OE}) input should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

PACKAGE⁽¹⁾ TA **ORDERABLE PART NUMBER TOP-SIDE MARKING** TSSOP - DGG Tape and reel SN74GTLPH1645DGGR GTLPH1645 –40°C to 85°C TVSOP - DGV Tape and reel SN74GTLPH1645DGVR GL45 VFBGA - GQL SN74GTLPH1645GQLR Tape and reel GL45

ORDERING INFORMATION

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.





TERMINAL ASSIGNMENTS

	1	2	3	4	5	6
Α	1A2	1A1	1DIR	1 0E	1B1	1B2
В	1A4	1A3	GND	GND	1B3	1B4
С	1A5	GND	V _{CC}	V _{CC}	GND	1B5
D	1A7	1A6	GND	GND	1B6	1B7
Е	GND	1A8			1B8	BIAS V_{CC}
F	ERC	2A1			2B1	V _{REF}
G	2A2	2A3	GND	GND	2B3	2B2
н	2A4	GND	V _{CC}	V _{CC}	GND	2B4
J	2A5	2A6	GND	GND	2B6	2B5
к	2A7	2A8	2DIR	2 <mark>0E</mark>	2B8	2B7

FUNCTIONAL DESCRIPTION

The SN74GTLPH1645 is a high-drive (100-mA), 16-bit bus transceiver partitioned as two 8-bit segments and is designed for asynchronous communication between data buses. The device transmits data from the A port to the B port or from the B port to the A port, depending on the logic level at the direction-control (DIR) input. \overline{OE} can be used to disable the device so the buses are effectively isolated. Data polarity is noninverting.

For A-to-B data flow, when \overline{OE} is low and DIR is high, the B outputs take on the logic value of the A inputs. When \overline{OE} is high, the outputs are in the high-impedance state.

The data flow for B to A is similar to A to B, except OE and DIR are low.

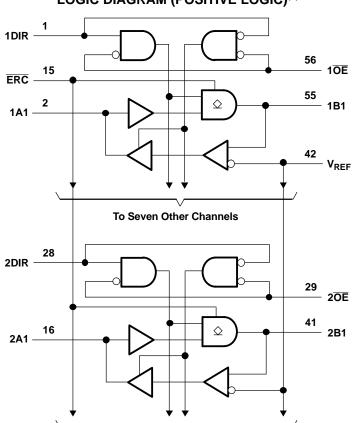
FUNCTION TABLES

OUTPUT CONTROL

INPUTS		OUTPUT	MODE				
ŌĒ	DIR	OUTFOI	MODE				
Н	Х	Z	Isolation				
L	L	B data to A port	True transporent				
L	Н	A data to B port	True transparent				

B-PORT EDGE-RATE CONTROL (ERC)

INPU	r erc	OUTPUT				
LOGIC LEVEL	NOMINAL VOLTAGE	B-PORT EDGE RATE				
L	GND	Slow				
н	V _{CC}	Fast				



LOGIC DIAGRAM (POSITIVE LOGIC)⁽¹⁾

To Seven Other Channels

(1) Pin numbers shown are for the DGG and DGV packages.

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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC} BIAS V _{CC}	Supply voltage range		-0.5	4.6	V
V	Input voltage renge (2)	A-port, ERC, and control inputs	-0.5	7	V
VI	Input voltage range ⁽²⁾	B port and V _{REF}	-0.5	4.6	v
M	Voltage range applied to any output in the	A port	-0.5	7	V
Vo	high-impedance or power-off state ⁽²⁾	B port	-0.5	4.6	V
	Current into any output in the low state A port B port			48	
0				200	mA
l _o	Current into any A-port output in the high state	(3)		48	mA
	Continuous current through each V_{CC} or GND			±100	mA
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V ₀ < 0		-50	mA
		DGG package		64	
θ_{JA}	Package thermal impedance ⁽⁴⁾	DGV package		48	°C/W
			42		
T _{stg}	Storage temperature range	· ·	-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(3) This current flows only when the output is in the high state and V_O > V_{CC}.
(4) The package thermal impedance is calculated in accordance with JESD 51-7.

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Recommended Operating Conditions⁽¹⁾⁽²⁾⁽³⁾⁽⁴⁾

			MIN	NOM	MAX	UNIT	
V _{CC} , BIAS V _{CC}	Supply voltage		3.15	3.3	3.45	V	
M	Termination voltage	GTL	1.14	1.2	1.26	V	
V _{TT}	Termination voltage	GTLP	1.35	1.5	1.65	V	
<i>\</i> /	Deference velkere	GTL	0.74	0.8	0.87	V	
V _{REF}	Reference voltage	GTLP	0.87	1	1.1	V	
<i>\</i> /		B port			V _{TT}	V	
VI	Input voltage	Except B port		V _{CC}	5.5	V	
		B port	V _{REF} + 0.05				
V _{IH}	High-level input voltage	ERC	V _{CC} – 0.6	V _{CC}	5.5	V	
		Except B port and ERC	2				
		B port			$V_{REF} - 0.05$		
V _{IL}	Low-level input voltage	ERC		GND	0.6	V	
		Except B port and ERC			0.8		
I _{IK}	Input clamp current				-18	mA	
I _{OH}	High-level output current	A port			-24	mA	
		A port			24		
I _{OL}	Low-level output current	B port			100	00 mA	
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled			10	ns/V	
$\Delta t / \Delta V_{CC}$	Power-up ramp rate		20			μs/V	
T _A	Operating free-air temperature		-40		85	°C	

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

 (2) Proper connection sequence for use of the B-port I/O precharge feature is GND and BIAS V_{CC} = 3.3 V first, I/O second, and V_{CC} = 3.3 V last, because the BIAS V_{CC} precharge circuitry is disabled when any V_{CC} pin is connected. The control and V_{REF} inputs can be connected anytime, but normally are connected during the I/O stage. If B-port precharge is not required, any connection sequence is acceptable but, generally, GND is connected first.

(3)

 V_{TT} and R_{TT} can be adjusted to accommodate backplane impedances if the dc recommended I_{OL} ratings are not exceeded. V_{REF} can be adjusted to optimize noise margins, but normally is two-thirds V_{TT} . TI-OPC circuitry is enabled in the A-to-B direction and is activated when $V_{TT} > 0.7$ V above V_{REF} . If operated in the A-to-B direction, V_{REF} should be set to within 0.6 V of V_{TT} to minimize current (4) drain.



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Electrical Characteristics

over recommended operating free-air temperature range for GTLP (unless otherwise noted)

P/	ARAMETER	TEST CONDITIONS		MIN 1	ГҮР ⁽¹⁾ М	AX	UNIT	
V _{IK}		V _{CC} = 3.15 V,	I _I = -18 mA			1.2	V	
	A port	V _{CC} = 3.15 V to 3.45 V,	I _{OH} = −100 μA	$V_{CC} - 0.2$				
V _{OH}		V 245V	I _{OH} = -12 mA	2.4			V	
		$V_{CC} = 3.15 V$	I _{OH} = -24 mA	2				
	A port	$V_{CC} = 3.15 \text{ V} \text{ to } 3.45 \text{ V},$	I _{OL} = 100 μA		(0.2		
		V 245V	I _{OL} = 12 mA		(0.4		
V _{OL}		$V_{CC} = 3.15 V$	I _{OL} = 24 mA		(0.5	V	
			I _{OL} = 10 mA		(0.2	v	
	B port	V _{CC} = 3.15 V	$I_{OL} = 64 \text{ mA}$		(0.4		
			I _{OL} = 100 mA		0.	55		
l _l	Control inputs	V _{CC} = 3.45 V,	V _I = 0 or 5.5 V		±	:10	μA	
I _{OZH} ⁽²⁾	A port		$V_0 = V_{CC}$			10		
	B port	$-V_{CC} = 3.45 V$	V _O = 1.5 V			10	μA	
I _{OZL} ⁽²⁾	A and B ports	V _{CC} = 3.45 V,	V _O = GND		_	-10	μA	
I _{BHL} ⁽³⁾	A port	V _{CC} = 3.15 V,	V _I = 0.8 V	75			μA	
I _{BHH} ⁽⁴⁾	A port	V _{CC} = 3.15 V,	V _I = 2 V	-75			μA	
I _{BHLO} ⁽⁵⁾	A port	V _{CC} = 3.45 V,	$V_I = 0$ to V_{CC}	500			μA	
I _{BHHO} ⁽⁶⁾	A port	V _{CC} = 3.45 V,	$V_I = 0$ to V_{CC}	-500			μA	
		$V_{CC} = 3.45 \text{ V}, \text{ I}_{O} = 0,$	Outputs high			40		
I _{CC}	A or B port	V_1 (A-port or control inputs) = V_{CC} or GND,	Outputs low			40	mA	
		V_{I} (B port) = V_{TT} or GND	Outputs disabled			40		
$\Delta I_{CC}^{(7)}$	· · · · · · · · · · · · · · · · · · ·	V_{CC} = 3.45 V, One A-port or control input at V Other A-port or control inputs at V _{CC} or GND	/ _{CC} – 0.6 V,			1.5	mA	
C _i	Control inputs	V _I = 3.15 V or 0			4	5	pF	
0	A port	V _O = 3.15 V or 0			6.5	7.5		
C _{io}	B port	V _O = 1.5 V or 0			9.5	11	pF	

 All typical values are at V_{CC} = 3.3 V, T_A = 25°C.
 For I/O ports, the parameters I_{OZH} and I_{OZL} include the input leakage current.
 The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL}max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to $V_{\text{IL}}\text{max}.$

(4) The bus-hold circuit can source at least the minimum high sustaining current at VIHmin. IBHH should be measured after raising VIN to VCC and then lowering it to $V_{\mbox{\scriptsize IH}}\mbox{min}.$

(5)

An external driver must source at least I_{BHLO} to switch this node from low to high. An external driver must sink at least I_{BHHO} to switch this node from high to low. (6)

(7) This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.

Hot-Insertion Specifications for A Port

over recommended operating free-air temperature range

PARAMETER		TEST CONDITIONS						
I _{off}	$V_{CC} = 0,$	BIAS $V_{CC} = 0$,	V_{I} or V_{O} = 0 to 5.5 V		10	μA		
I _{OZPU}	$V_{CC} = 0$ to 1.5 V,	$V_{O} = 0.5 V$ to 3 V,	$\overline{OE} = 0$		±30	μA		
I _{OZPD}	$V_{CC} = 1.5 V \text{ to } 0,$	$V_{O} = 0.5 V$ to 3 V,	$\overline{OE} = 0$		±30	μA		

Live-Insertion Specifications for B Port

over recommended operating free-air temperature range

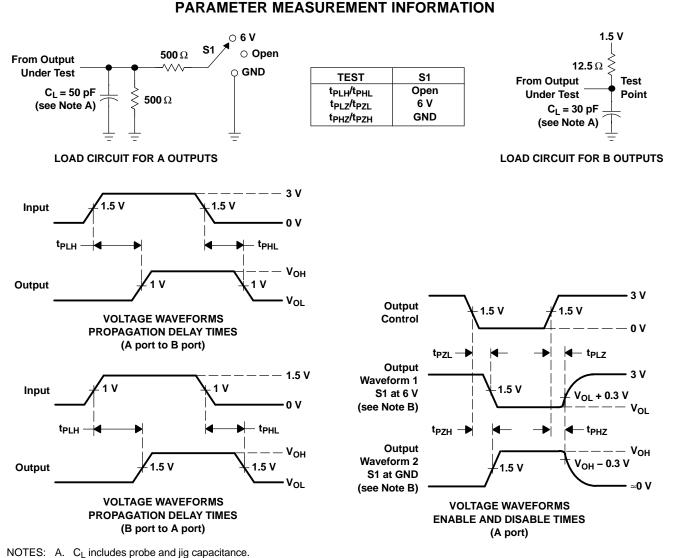
PARAMETER		TEST CONDITIONS		MIN	MAX	UNIT
I _{off}	$V_{CC} = 0,$	BIAS $V_{CC} = 0$,	V_{I} or V_{O} = 0 to 1.5 V		10	μA
I _{OZPU}	$V_{CC} = 0$ to 1.5 V,	BIAS $V_{CC} = 0$,	$V_0 = 0.5 \text{ V} \text{ to } 1.5 \text{ V}, \overline{\text{OE}} = 0$		±30	μA
I _{OZPD}	$V_{CC} = 1.5 V \text{ to } 0,$	BIAS $V_{CC} = 0$,	$V_0 = 0.5 \text{ V to } 1.5 \text{ V}, \overline{\text{OE}} = 0$		±30	μA
	$V_{CC} = 0$ to 3.15 V		V_{O} (B port) = 0 to 1.5 V		5	mA
I_{CC} (BIAS V_{CC})	V_{CC} = 3.15 V to 3.45 V	BIAS V_{CC} = 3.15 V to 3.45 V,	v_0 (B poil) = 0 to 1.5 v		10	μA
Vo	$V_{CC} = 0,$	BIAS $V_{CC} = 3.3 V$,	l _O = 0	0.95	1.05	V
Ι _Ο	$V_{CC} = 0,$	BIAS V_{CC} = 3.15 V to 3.45 V,	V _O (B port) = 0.6 V	-1		μA

Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature, V_{TT} = 1.5 V and V_{REF} = 1 V for GTLP (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	EDGE RATE ⁽¹⁾	MIN	TYP ⁽²⁾	MAX	UNIT	
t _{PLH}	А	В	Slow	3.9		7.2	20	
t _{PHL}	A	D	310W	3.1		8.4	ns	
t _{PLH}	А	В	Fast	2.6		5.7	ns	
t _{PHL}	A	В	T dSt	2.1		5.8	115	
t _{en}	ŌĒ	В	Slow	4.1		7.3	200	
t _{dis}	OL	В	SIOW	4		9.4	ns	
t _{en}	OE	В	Fast	2.9		5.9	ns	
t _{dis}	OL	В	T dSt	4		6.9	115	
+	Pico timo Routo	uts (20% to 80%)	Slow		3			
t _r			Fast		1.5		ns	
+.	Fall time Boute	utc (80% to 20%)	Slow		4		200	
t _f		uts (80% to 20%)	Fast	2.5			ns	
t _{PLH}	В	А		0.5		6.7	ns	
t _{PHL}	0	A		1.2		4.5	115	
t _{en}	ŌĒ	А		1.1		6.3	nc	
t _{dis}	UL	~		1.7		5.1	ns	

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- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \approx 10 MHz, Z_O = 50 Ω , t_r \approx 2 ns, t_f \approx 2 ns.
- D. The outputs are measured one at a time, with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms

Distributed-Load Backplane Switching Characteristics

The preceding switching characteristics table shows the switching characteristics of the device into a lumped load (Figure 1). However, the designer's backplane application probably is a distributed load. The physical representation is shown in Figure 2. This backplane, or distributed load, can be approximated closely to a resistor inductance capacitance (RLC) circuit, as shown in Figure 3. This device has been designed for optimum performance in this RLC circuit. The following switching characteristics table shows the switching characteristics of the device into the RLC load, to help the designer better understand the performance of the GTLP device in this typical backplane. See www.ti.com/sc/gtlp for more information.

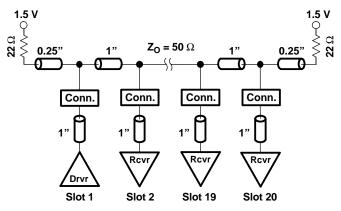


Figure 2. High-Drive Test Backplane

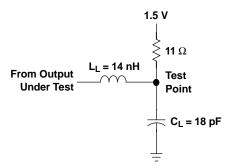


Figure 3. High-Drive RLC Network



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Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature, $V_{\rm TT}$ = 1.5 V and $V_{\rm REF}$ = 1 V for GTLP (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	EDGE RATE ⁽¹⁾	TYP ⁽²⁾	UNIT	
t _{PLH}	- A	В	Slow	4.9	ns	
t _{PHL}	~	D	Siow	4.9	115	
t _{PLH}	- A	В	Fast	3.7	200	
t _{PHL}	A	D	rasi	3.7	ns	
t _{en}	- OE	В	Slow	5.1	ns	
t _{dis}		D	510W	5.4		
t _{en}		В	Fast	4.1	ns	
t _{dis}	OL	В	Fasi	4.1		
+	Diag time. Diguta	(200/ to 900/)	Slow	2	ns	
tr	Rise time, B outp	0015 (20% 10 00%)	its (20% to 80%) Fast			
+	Fall time. Plaute	(80%) to $20%$	Slow	2.5	20	
t _f	Pair time, B outp	uts (80% to 20%)	Fast	1.8	ns	

(1) Slow (ERC = GND) and Fast (ERC = V_{CC}) (2) All typical values are at V_{CC} = 3.3 V, T_A = 25°C. All values are derived from TI-SPICE models.



26-Aug-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)		(3)		(4/5)	
74GTLPH1645DGGRE4	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	GTLPH1645	Samples
74GTLPH1645DGGRG4	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	GTLPH1645	Samples
74GTLPH1645DGVRE4	ACTIVE	TVSOP	DGV	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	GL45	Samples
74GTLPH1645DGVRG4	ACTIVE	TVSOP	DGV	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	GL45	Samples
SN74GTLPH1645DGGR	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	GTLPH1645	Samples
SN74GTLPH1645DGVR	ACTIVE	TVSOP	DGV	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	GL45	Samples
SN74GTLPH1645GQLR	OBSOLETE	BGA MICROSTAR JUNIOR	GQL	56		TBD	Call TI	Call TI	-40 to 85	GL45	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



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(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74GTLPH1645DGGR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1
SN74GTLPH1645DGVR	TVSOP	DGV	56	2000	330.0	24.4	6.8	11.7	1.6	12.0	24.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74GTLPH1645DGGR	TSSOP	DGG	56	2000	367.0	367.0	45.0
SN74GTLPH1645DGVR	TVSOP	DGV	56	2000	367.0	367.0	45.0

MECHANICAL DATA

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

DGV (R-PDSO-G**)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

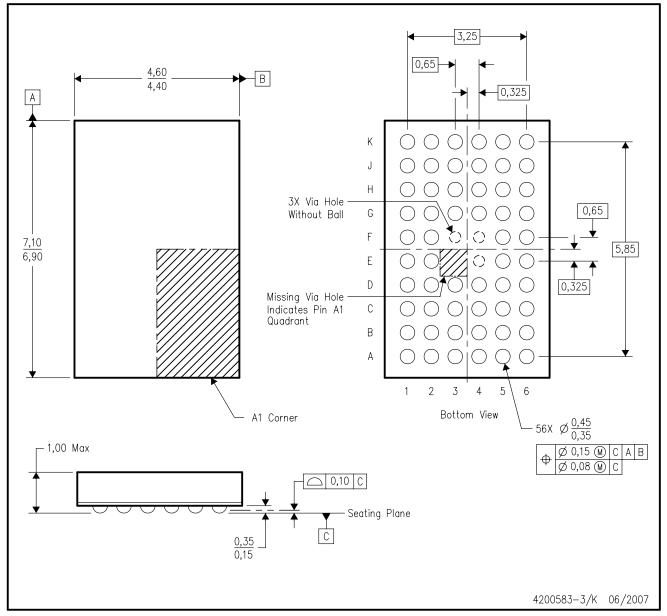
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



MECHANICAL DATA

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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